查询2SA1015供应商 TOSHIBA

2SA1015(L)

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

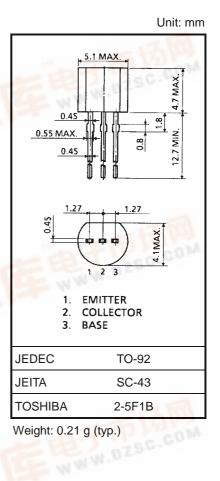
2SA1015(L)

Audio Frequency Amplifier Applications Low Noise Amplifier Applications

- High voltage and high current: $V_{\rm CEO}$ = –50 V (min),
 - $I_{C} = -150 \text{ mA} \text{ (max)}$
- Excellent hFE linearity: hFE (2) = 80 (typ.) at VCE = -6 V, IC = -150 mA: hFE (IC = -0.1 mA)/hFE (IC = -2 mA) = 0.95 (typ.)
- Low noise: NF = 0.2dB (typ.) (f = 1 kHz)
- Complementary to 2SC1815 (L)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	-50	V	
Collector-emitter voltage	V _{CEO}	-50	V	
Emitter-base voltage	V _{EBO}	-5	V	
Collector current	Ic	-150	mA	
Base current	I _B	-50	mA	
Collector power dissipation	P _C	400	mW	
Junction temperature	Тј	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



Electrical Characteristics (Ta = 25°C)

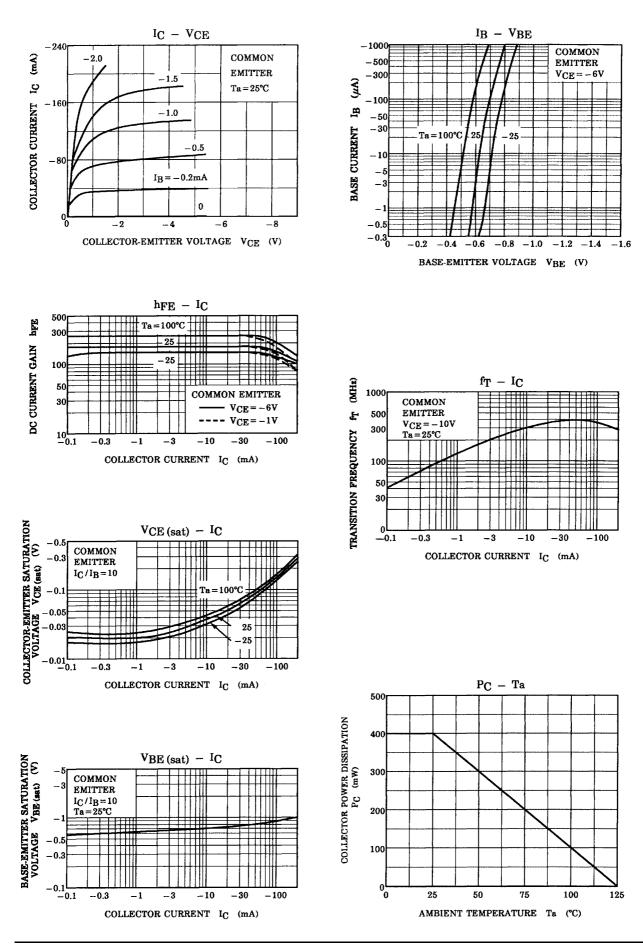
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{СВО}	$V_{CB} = -50 \text{ V}, \text{ I}_{E} = 0$			-0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 V, I_C = 0$			-0.1	μA
DC current gain	h _{FE (1)} (Note)	$V_{CE} = -6 \text{ V}, \text{ I}_{C} = -2 \text{ mA}$	70	_	400	60
	h _{FE (2)}	$V_{CE} = -6 \text{ V}, I_C = -150 \text{ mA}$	25	80	1	CON
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{\rm C} = -100 \text{ mA}, I_{\rm B} = -10 \text{ mA}$		-0.1	-0.3	V
Base-emitter saturation voltage	V _{BE (sat)}	$I_{\rm C} = -100 \text{ mA}, I_{\rm B} = -10 \text{ mA}$	1		-1.1	V
Transition frequency	fT	$V_{CE} = -10 \text{ V}, \text{ I}_{C} = -1 \text{ mA}$	80			MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0$ f = 1 MHz		4	7	pF
Base intrinsic resistance	r _{bb} ,	$V_{CB} = -10 \text{ V}, \text{ I}_E = 1 \text{ mA}$ f = 30 MHz		30	_	Ω
Noise figure	NF (1)	$\label{eq:Vce} \begin{array}{l} V_{CE}=-6 \ V, \ I_C=-0.1 \ mA \\ f=100 \ Hz, \ R_G=10 \ k\Omega \end{array}$		0.5	6	dB
	NF (2)	$\label{eq:Vce} \begin{array}{l} V_{CE}=-6 \ V, \ I_{C}=-0.1 \ mA \\ f=1 \ kHz, \ R_{G}=10 \ k\Omega \end{array}$		0.2	3	

Note: hFE (1) classification O: 70~140, Y: 120~240, GR: 200~400

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